




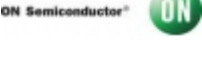



	<h2 style="color: red;">FQP13N50C</h2>
	<p>Hersteller-Teilenummer: FQP13N50C</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 500V 13A TO-220</p> <p>Datenblätter: 1.FQP13N50C.pdf 2.FQP13N50C.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 32059 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP13N50C
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 500V 13A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32059 pcs Stock
detaillierte Beschreibung	N-Channel 500V 13A (Tc) 195W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	195W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	13A (Tc)
Rds On (Max) @ Id, Vgs	480 mOhm @ 6.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	56nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2055pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQP13N50C ist neu im Original, Suche FQP13N50C Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP13N50C AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP13N50C: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP13N50 Fairchild/ON Semiconductor MOSFET N-CH 500V 12.5A TO-220</p>	 <p>FQP140N03 Fairchild/ON Semiconductor FQP140N03 FAIRCHILD</p>	 <p>FQP13N50C Fairchild/ON Semiconductor MOSFET N-CH 500V 13A TO-220</p>	 <p>FQP13N10L Fairchild/ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>
 <p>FQP13N50C_F105 AMI Semiconductor / ON Semiconductor IC POWER MANAGEMENT</p>	 <p>FQP140N03L Original FQP140N03L Original</p>	 <p>FQP14N15 Fairchild/ON Semiconductor MOSFET N-CH 150V 14.4A TO-220</p>	 <p>FQP13N10L AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 12.8A TO-220</p>

heiße Teile

Mehr

⊗ FQP11N60	↔ FQP11N60C	⇒ FQP11N65C	D FQP11P06	↔ FQP11P06
⊣ FQP12N20	⊗ FQP12N60	D FQP12N60	⇒ FQP12N60C	↔ FQP12N60C
⊗ FQP12N65C	⊣ FQP12P10	⊗ FQP12P10	↔ FQP12P20	↔ FQP12P20
D FQP13N06	⊗ FQP13N06	⊣ FQP13N06L	⊗ FQP13N06L	↔ FQP13N10
⇒ FQP13N10	↔ FQP13N10L	⊗ FQP13N10L	⊣ FQP13N50	↔ FQP13N50
↔ FQP13N50C	⇒ FQP13N60C	D FQP140N03	⊗ FQP140N03L	⊣ FQP14N15
⊗ FQP14N15	D FQP14N30	⇒ FQP14N30	↔ FQP14N80	↔ FQP14N80C
⊣ FQP15N16	⊗ FQP15N30	↔ FQP15N50	⇒ FQP15N60	↔ FQP15N65
⊗ FQP15N80	⊣ FQP15P12	⊗ FQP15P12	D FQP16N15	↔ FQP16N15
↔ FQP16N25	⊗ FQP16N25	⊣ FQP16N25C	⊗ FQP16N25C	↔ FQP17N08

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